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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# MOS FIELD EFFECT TRANSISTOR



### **SWITCHING** P-CHANNEL POWER MOS FET

#### **DESCRIPTION**

The μPA2710GR is P-Channel MOS Field Effect Transistor designed for power management applications of notebook computers and Li-ion battery protection circuit.

#### **FEATURES**

· Low on-state resistance

RDS(on)1 =  $5.5 \text{ m}\Omega$  MAX. (Vgs = -10 V, ID = -7.5 A)

 $R_{DS(on)2} = 9.0 \text{ m}\Omega \text{ MAX}. \text{ (Vgs} = -4.5 \text{ V}, \text{ ID} = -7.5 \text{ A)}$ 

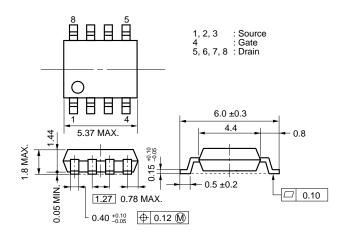
RDS(on)3 = 11 m $\Omega$  MAX. (VGS = -4.0 V, ID = -7.5 A)

- Low Ciss: Ciss = 4300 pF TYP.
  - Small and surface mount package (Power SOP8)

#### ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA2710GR	Power SOP8

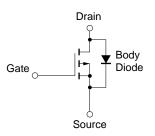
#### PACKAGE DRAWING (Unit: mm)



#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

Drain to Source Voltage (Vgs = 0 V)	$V_{\text{DSS}}$	-30	V
Gate to Source Voltage (VDS = 0 V)	Vgss	∓20	V
Drain Current (DC)	$I_{D(DC)}$	∓15	Α
Drain Current (pulse) Note1	I <sub>D(pulse)</sub>	∓100	Α
Total Power Dissipation Note2	P <sub>T1</sub>	2	W
Total Power Dissipation Note3	P <sub>T2</sub>	2	W
Channel Temperature	$T_ch$	150	°C
Storage Temperature	$T_{stg}$	-55 to + 150	°C
Single Avalanche Current Note4	las	<b>–15</b>	Α
Single Avalanche Energy Note4	Eas	22.5	mJ

#### **EQUIVALENT CIRCUIT**



- **Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%
  - 2. Mounted on ceramic substrate of 1200 mm<sup>2</sup> x 2.2 mm
  - 3. Mounted on a glass epoxy board (1 inch x 1 inch x 0.8 mm), PW = 10 sec
  - 4. Starting T<sub>ch</sub> = 25°C, V<sub>DD</sub> = -15 V, R<sub>G</sub> = 25  $\Omega$ , L = 100  $\mu$ H, V<sub>GS</sub> =  $-20 \rightarrow 0$  V

Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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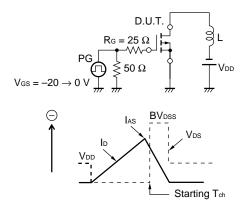


#### ★ ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)

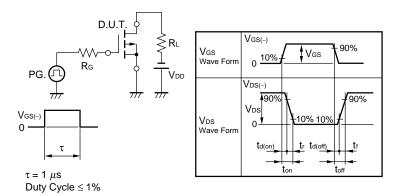
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μΑ
Gate Leakage Current	lgss	V <sub>GS</sub> = ∓20 V, V <sub>DS</sub> = 0 V			∓100	nA
Gate Cut-off Voltage Note	V <sub>GS(off)</sub>	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$	-1.0		-2.5	V
Forward Transfer Admittance <sup>Note</sup>	<b>y</b> fs	$V_{DS} = -10 \text{ V}, I_{D} = -7.5 \text{ A}$	14	31		S
Drain to Source On-state Resistance Note	RDS(on)1	$V_{GS} = -10 \text{ V}, I_{D} = -7.5 \text{ A}$		4.7	5.5	mΩ
	RDS(on)2	$V_{GS} = -4.5 \text{ V}, I_D = -7.5 \text{ A}$		6.4	9.0	mΩ
	RDS(on)3	$V_{GS} = -4.0 \text{ V}, I_D = -7.5 \text{ A}$		7.2	11	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = -10 V		4300		рF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V		1200		рF
Reverse Transfer Capacitance	Crss	f = 1 MHz		690		рF
Turn-on Delay Time	td(on)	$V_{DD} = -15 \text{ V}, I_{D} = -7.5 \text{ A}$		11		ns
Rise Time	tr	Vgs = -10 V		22		ns
Turn-off Delay Time	td(off)	Rg = 10 Ω		420		ns
Fall Time	tf			240		ns
Total Gate Charge	Qg	V <sub>DD</sub> = -24 V		97		nC
Gate to Source Charge	Qgs	Vgs = -10 V		12		nC
Gate to Drain Charge	Q <sub>GD</sub>	ID = -15 A		29		nC
Body Diode Forward Voltage	V <sub>F(S-D)</sub>	IF = 15 A, VGS = 0 V		0.79		٧
Reverse Recovery Time	trr	IF = 15 A, VGS = 0 V		119		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/μs		84		nC

**Note** Pulsed PW≤350 μs, Duty Cycle≤2%

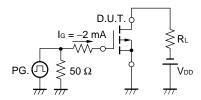
#### **TEST CIRCUIT 1 AVALANCHE CAPABILITY**



#### TEST CIRCUIT 2 SWITCHING TIME



#### **TEST CIRCUIT 3 GATE CHARGE**



%

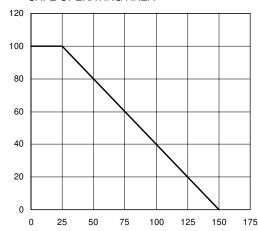
dT - Percentage of Rated Power -

lo - Drain Current - A



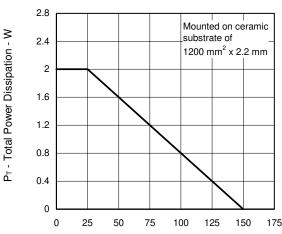
#### TYPICAL CHARACTERISTICS (TA = 25°C)

## DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



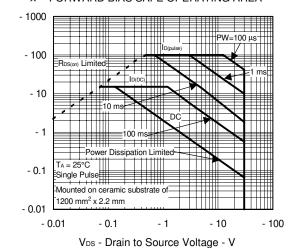
T<sub>A</sub> - Ambient Temperature - °C

## TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE

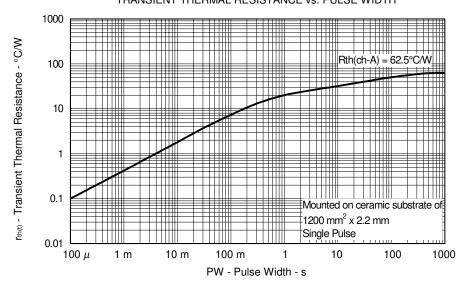


T<sub>A</sub> - Ambient Temperature - °C

#### ★ FORWARD BIAS SAFE OPERATING AREA



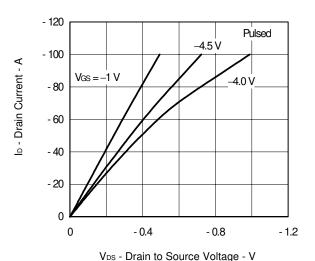
#### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



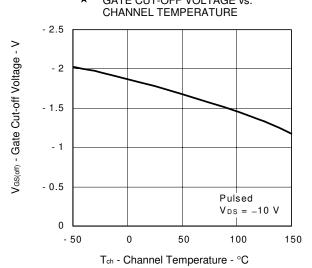
y<sub>fs</sub> | - Forward Transfer Admittance - S

 $\mathsf{R}_{\mathsf{DS}(m)}$  - Drain to Source On-state Resistance -  $\mathsf{m}\Omega$ 

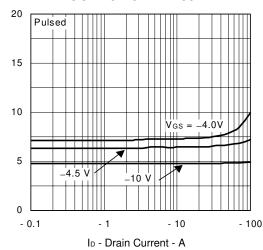
## ★ DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



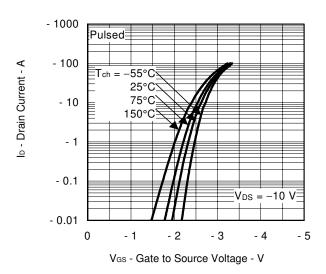
★ GATE CUT-OFF VOLTAGE vs.



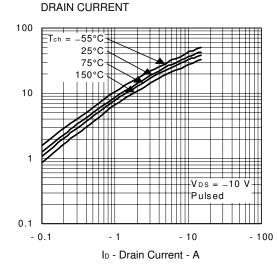
★ DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



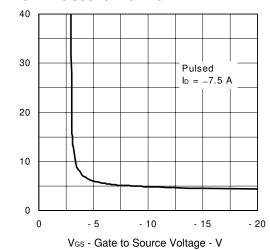
#### ★ FORWARD TRANSFER CHARACTERISTICS



★ FORWARD TRANSFER ADMITTANCE vs.



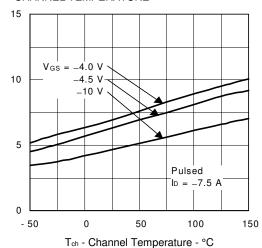
★ DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



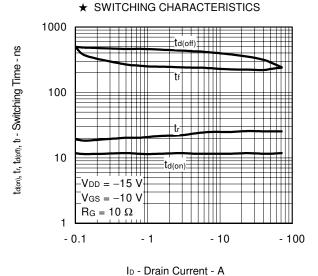
RDS(cn) - Drain to Source On-state Resistance - m\Omega

R<sub>DS(m)</sub> - Drain to Source On-state Resistance - mΩ

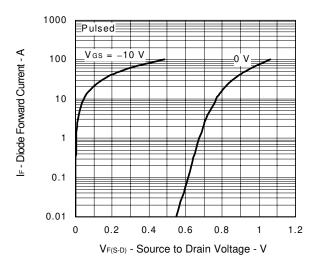
#### ★ DRAIN TO SOURCE ON-STATERESISTANCE vs. CHANNEL TEMPERATURE



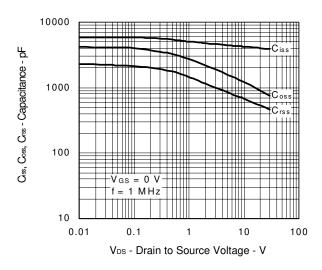
#### OWITOLING OUADAOTEDIOTION



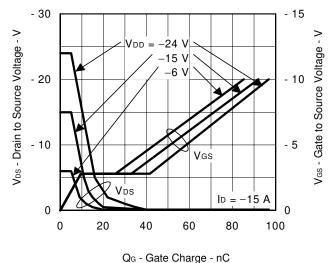
#### ★ SOURCE TO DRAIN DIODE FORWARD VOLTAGE



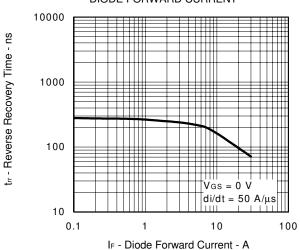
#### ★ CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



#### **★** DYNAMIC INPUT/OUTPUT CHARACTERISTICS

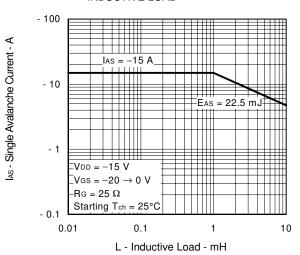


★ REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

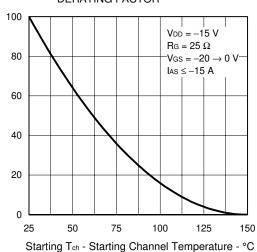


Energy Derating Factor - %

## SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



SINGLE AVALANCHE ENERGY DERATING FACTOR





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